NSN 5961-01-168-3039

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-168-3039 **Inclosure Material:** Plastic and metal **Overall Length:** 0.435 inches **Terminal Length:** 0.575 inches **Overall Height:** 0.105 inches **Overall Width:** 0.305 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-225aa **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 repetitive peak off-state voltage and 100.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 4.00 amperes drain current horsepower metric and 20.00 amperes peak forward surge current absolute **Maximum Operating Tempurature Per Measurement Point:** 110.0 degrees celsius junction **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0